PRELIMINARY



CGH35015F 15 W, 3300-3900 MHz, 28V, GaN HEMT for WiMAX

Cree's CGH35015F is a gallium nitride (GaN) high electron mobility transistor designed specifically for 802.16-2004 WiMAX Fixed Access applications. GaN HEMTs offer high efficiency, high gain and wide bandwidth capabilities, which makes the CGH35015F ideal for 3.3-3.9GHz WiMAX and BWA amplifier applications. The transistor is available in a flange package.



Package Type: 440166 PN: CGH35015F

Typical Performance 3.4-3.9GHz ($T_c = 25^{\circ}C$)

Parameter	3.4 GHz	3.5 GHz	3.6 GHz	3.8 GHz	3.9 GHz	Units
Gain @ P _{out} = 2 W	11.6	11.8	12.0	11.8	11.2	dB
P _{out} @ 2.0 % EVM	33.0	33.0	33.0	33.5	33.5	dBm
Drain Efficiency @ 2.0 % EVM	23.0	23.0	24.0	18.0	17.0	%
Input Return Loss	4.0	4.5	6.0	13.0	9.0	dB

Note:

Measured in the CGH35015F-TB amplifier circuit, under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, 5 ms Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3.

Features

- 3.3 3.9 GHz Operation
- >11 dB Small Signal Gain
- >2.0 W P_{out} at 2.0 % EVM
- 24 % Efficiency at 2.0 W P_{out}
- 15 W Typical P_{3dB}
- WiMAX Fixed Access 802.16-2004 OFDM



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Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V _{DSS}	84	Volts
Gate-to-Source Voltage	V _{GS}	-10, +2	Volts
Storage Temperature	T _{STG}	-55, +150	°C
Operating Junction Temperature	Т,	175	°C
Thermal Resistance, Junction to Case 1	R _{eJC}	5.0	°C/W

Note:

 $^{\rm 1}$ Measured for the CGH35015F at $\rm P_{\rm DISS}$ = 14W.

Electrical Characteristics ($T_c = 25^{\circ}C$)

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions	
DC Characteristics							
Gate Threshold Voltage	$V_{GS(th)}$	-3.0	-2.5	-1.8	VDC	$V_{_{\rm DS}}$ = 10 V, $I_{_{\rm D}}$ = 3.6 mA	
Gate Quiescent Voltage	$V_{GS(Q)}$	-	-2.4	-	VDC	$V_{_{\rm DS}}$ = 28 V, $I_{_{\rm D}}$ = 60 mA	
Saturated Drain Current	I _{ds}	2.4	2.7	-	А	$V_{_{DS}}$ = 6.0 V, $V_{_{GS}}$ = 2.0 V	
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	84	100	-	VDC	V_{gs} = -8 V, I_{d} = 3.6 mA	
Case Operating Temperature	T _c	-10	-	+105	°C		
Screw Torque	т	-	-	60	in-oz	Reference 440166 Package Revision 3	
RF Characteristics ^{2,3} ($T_c = 25^{\circ}C$, $F_0 = 3.5$ GHz unless otherwise noted)							
Small Signal Gain	G _{ss}	11	12	-	dB	V_{DD} = 28 V, I_{DQ} = 60 mA	
Drain Efficiency ¹	η	22	24	-	%	$V_{_{\rm DD}}$ = 28 V, $I_{_{\rm DQ}}$ = 60 mA, $P_{_{\rm AVE}}$ = 2.0 W	
Back-Off Error Vector Magnitude	EVM ₁	-	2.5	-	%	$V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 60 mA, $P_{_{AVE}}$ = 18 dBm	
Error Vector Magnitude	EVM ₂	-	2.0	-	%	$V_{_{\rm DD}}$ = 28 V, $I_{_{\rm DQ}}$ = 60 mA, $P_{_{\rm AVE}}$ = 2.0 W	
Output Mismatch Stress	VSWR	-	10:1	-	Ψ	No damage at all phase angles, $V_{_{\rm DD}}$ = 28 V, $I_{_{\rm DQ}}$ = 60 mA, $P_{_{\rm AVE}}$ = 2.0 W	
Dynamic Characteristics							
Input Capacitance	C _{GS}	-	5.00	-	pF	$\rm V_{_{DS}}$ = 28 V, $\rm V_{_{gs}}$ = -8 V, f = 1 MHz	
Output Capacitance	C _{DS}	-	1.32	-	pF	$\rm V_{_{DS}}$ = 28 V, $\rm V_{_{gs}}$ = -8 V, f = 1 MHz	
Feedback Capacitance	C _{GD}	-	0.43	-	pF	$V_{_{\rm DS}}$ = 28 V, $V_{_{\rm gs}}$ = -8 V, f = 1 MHz	
NI-L							

Notes:

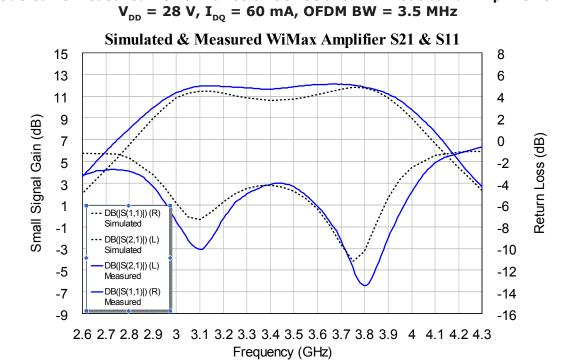
¹ Drain Efficiency = P_{out} / P_{bc} ² Under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, 5 ms Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3.

³ Measured in the CGH35015F-TB test fixture.

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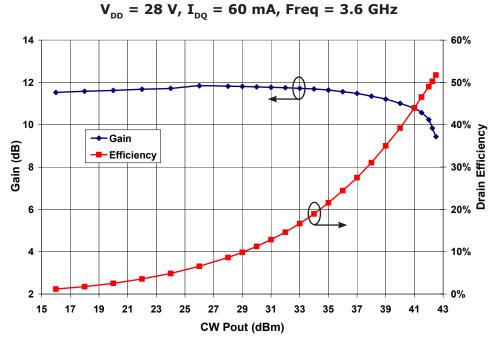


Typical WiMAX Performance



Modeled vs Measured Performance of CGH35015F in Broadband Amplifier Circuit



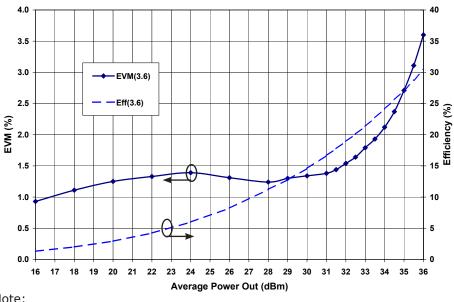


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Typical WiMAX Performance

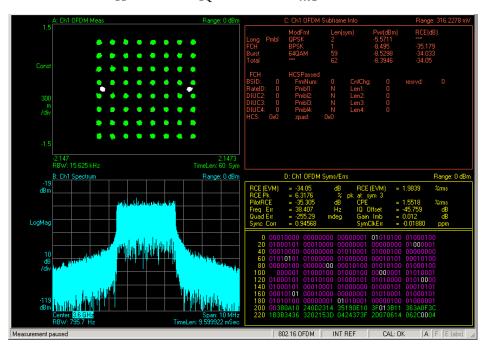


Typical EVM and Efficiency of CGH35015F in Broadband Amplifier Circuit at 3.6 GHz F=3.6 GHz, 802.16-2004 OFDM, P/A=9.8 dB

Note:

Under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3.

Typical Constellation Chart, Spectral Mask, and EVM of CGH35015F in Broadband Amplifier Circuit at 3.6 GHz $V_{DD} = 28 V, I_{DO} = 60 mA, P_{AVE} = 2.0 W$

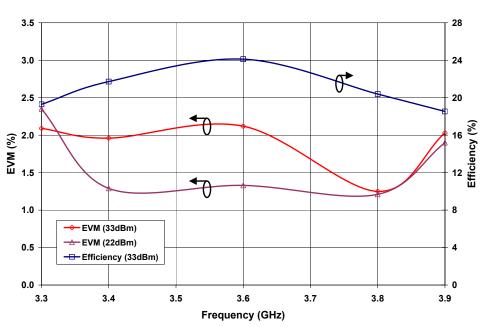


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Typical WiMAX Performance





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Note:

Under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3.

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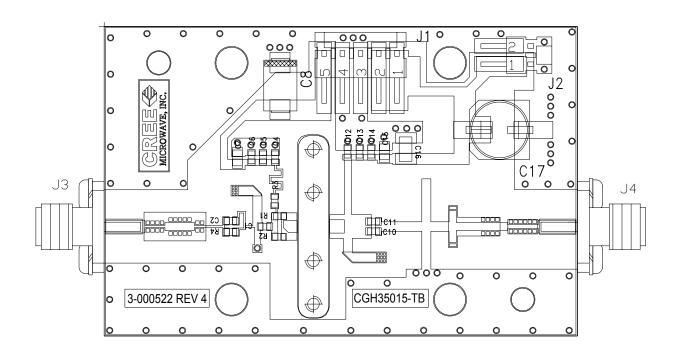
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CGH35015F-TB Demonstration Amplifier Circuit



CGH35015F-TB Demonstration Amplifier Circuit Outline



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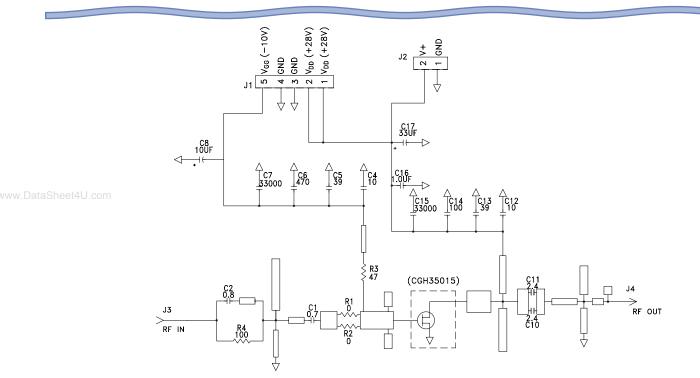
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CGH35015F Rev 1.6 Preliminary

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CGH35015F-TB Demonstration Amplifier Circuit Schematic



CGH35015F-TB Demonstration Amplifier Circuit Bill of Materials

Designator	Description	Qty
C1	CAP, 0.7pF, +/-0.1 pF, 0603, ATC 600S	1
C2	CAP, 0.8pF, +/-0.1 pF, 0603, ATC 600S	1
C10,C11	CAP, 2.4pF,+/-0.1pF, 0603, ATC 600S	2
C4	CAP, 10.0pF, +/-5%, 0603, ATC 600S	1
C5,C13	CAP, 39 PF±5%, 0603, ATC 600S	2
C14	CAP, 100 PF±5%, 0603, ATC 600S	1
C6	CAP, 470 PF ±10%,100 V, 0603	1
C7,C15	CAP, 33000PF, 100V, 0805, X7R	2
C8	CAP, 10UF, 16V, SMT, TANTALUM (240096)	1
C16	CAP, 1.0UF ±10%, 100V, 1210, X7R	1
C17	CAP, 33UF, 100V, ELECT, FK, SMD	1
R1,R2	RES, 1/16W, 0603, 0 Ohms, 1%	2
R3	RES, 1/16W, 0603, 47 Ohms ≤5%	1
R4	RES, 1/16W, 0603, 100 Ohms ≤5%	1
J1	5-PIN, MOLEX, MALE, CONNECTOR	1
J2	2-PIN, MOLEX, MALE, CONNECTOR	1
33,34	SMA, FEMALE, CONNECTOR	2
Q1	CGH35015	1

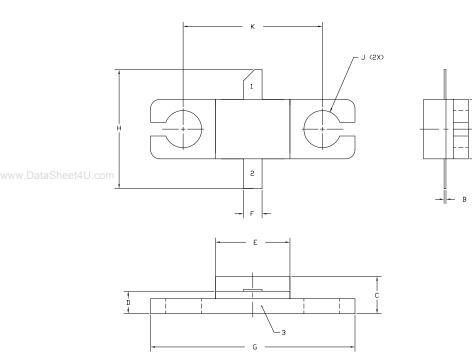
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Product Dimensions CGH35015F (Package Type – 440166)



NDTES:

1. DIMENSIONING AND TOLERANICING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.

4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008' IN ANY DIRECTION.

5. ALL PLATED SURFACES ARE NI/AU

1		INIO	HES	MILLIMETERS		
		INC	HES	MILLIMETERS		
	DIM	MIN	MAX	MIN	MAX	
	A	0.155	0.165	3.94	4.19	
	В	0.004	0.006	0.10	0.15	
	С	0.115	0.135	2.92	3.43	
	D	0.057	0.067	1.45	1.70	
	E	0.195	0.205	4.95	5.21	
	F	0.045	0.055	1.14	1.40	
	G	0.545	0.555	13.84	14.09	
	н	0.280	0.360	7.87	8.38	
	J	ø.	100	2.54		
	к	0.3	75	9.53		

PIN 1. GATE PIN 2. DRAIN PIN 3. SOURCE

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